

N-Ch MOSFET

General Description

The WST2N7002A is the highest performance trench N-Ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the small power switching and load switch applications.

The WST2N7002A meet the RoHS and Green Product requirement with full function reliability approved.

Features

- High-speed switching
- Green Device Available
- ESD Protected:2KV

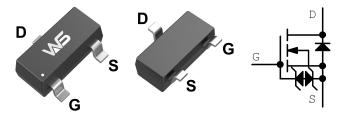
Product Summery

BVDSS	RDSON	ID
60V	0.14Ω	700mA

Applications

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC
- Networking DC-DC Power System

SOT-23N Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units	
V _{DS}	Drain-Source Voltage	60	V	
V _{GS}	Gate-Source Voltage	±20	V	
I _D @T _A =25℃	Continuous Drain Current, V _{GS} @ 10V ¹	700	mA	
I _D @T _A =70℃	Continuous Drain Current, V _{GS} @ 10V ¹	350	mA	
I _{DM}	Pulsed Drain Current ²	2.0	A	
P _D @T _A =25℃	Total Power Dissipation ³	0.25	W	
T _{STG}	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150	°C	

Thermal Data

Symbol	Parameter	Тур.	Max.	Unit
R _{θJA}	Thermal Resistance Junction-Ambient ¹		625	°C/W



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Electrical Characteristics (T_J=25⁻C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	60			V
$\triangle BV_{DSS} / \triangle T_{J}$	BV _{DSS} Temperature Coefficient	Reference to 25° C , I _D =1mA		0.05		V/℃
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =0.5A		0.14	0.45	Ω
		V _{GS} =4.5V , I _D =0.2A		0.18	0.765	
V _{GS(th)}	Gate Threshold Voltage		0.5		3.0	V
	V _{GS(th)} Temperature Coefficient			-3.7		mV/℃
I _{DSS}	Drain-Source Leakage Current	V_{DS} =60V , V_{GS} =0V , T_{J} =25 $^{\circ}$ C			1	
		V_{DS} =60V , V_{GS} =0V , T_{J} =55 $^{\circ}$ C			5	uA
I _{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm20V$, $V_{DS}=0V$			±10	uA
gfs	Forward Transconductance	V _{DS} =5V , I _D =0.3A		300		mS
T _{d(on)}	Turn-On Delay Time			6	10	
Tr	Rise Time	V_{DD} =30V , V_{GS} =10V , R_G =3.3 Ω ,		8.2	9.5	
T _{d(off)}	Turn-Off Delay Time	I _D =0.5A		28	35	ns
T _f	Fall Time			10	13.6	
C _{iss}	Input Capacitance			130	350	
C _{oss}	Output Capacitance	V _{DS} =25V , V _{GS} =0V , f=1MHz		70	120	pF
C _{rss}	Reverse Transfer Capacitance			25	36	

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
ls	Continuous Source Current ^{1,4}	$-V_G=V_D=0V$, Force Current			700	mA
I _{SM}	Pulsed Source Current ^{2,4}				2.0	A
V _{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25℃			1	V

Note :

1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

2. The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2% 3. The power dissipation is limited by 150 °C junction temperature.

4. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



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Typical Characteristics

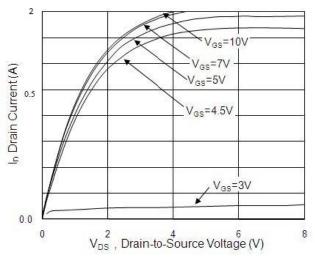


Fig.1 Typical Output Characteristics

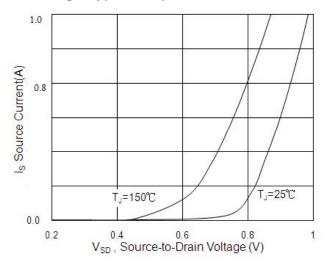


Fig.3 Forward Characteristics of Reverse

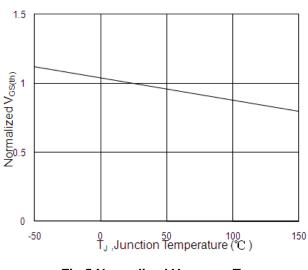
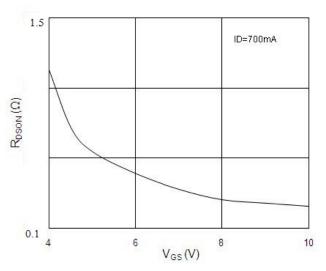
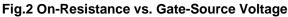


Fig.5 Normalized V_{GS(th)} vs. T_J





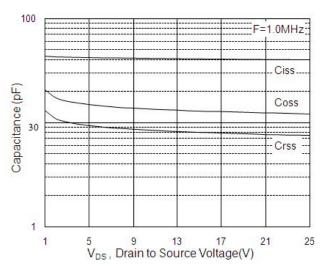


Fig.4 Capacitance

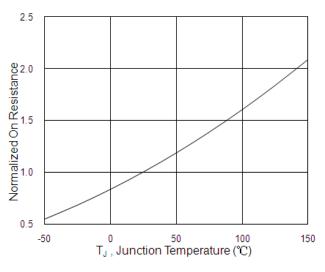


Fig.6 Normalized R_{DSON} vs. T_J



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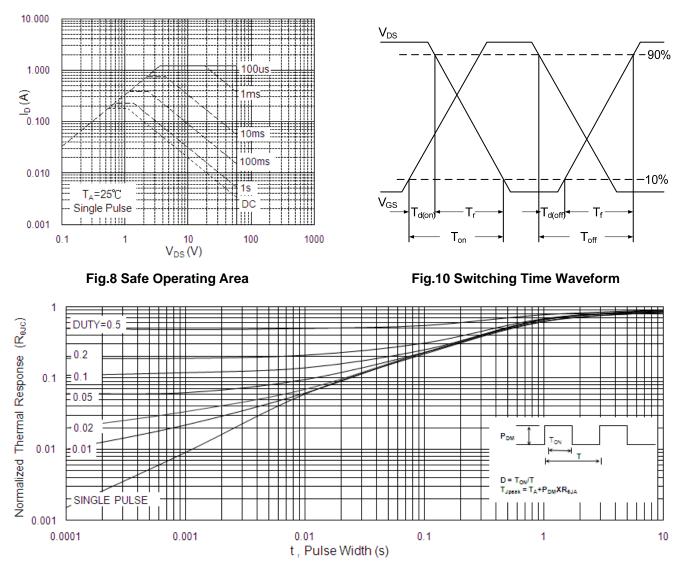


Fig.9 Normalized Maximum Transient Thermal Impedance



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